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Kind regards,

Team Nexperia

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

Rev. 5 — 21 December 2011

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistor (RET) family in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package		NPN Package		_
	NXP	JEITA	JEDEC	complement	configuration
PDTA123JE	SOT416	SC-75	-	PDTC123JE	ultra small
PDTA123JM	SOT883	SC-101	-	PDTC123JM	leadless ultra small
PDTA123JT	SOT23	-	TO-236AB	PDTC123JT	small
PDTA123JU	SOT323	SC-70	-	PDTC123JU	very small

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital application in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		1.54	2.20	2.86	kΩ
R2/R1	bias resistor ratio		17	21	26	



2. Pinning information

Pinning Table 3. Pin Description Simplified outline **Graphic symbol** SOT23; SOT323; SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym003 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

3. Ordering information

Table 4. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTA123JE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA123JM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTA123JT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA123JU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTA123JE	27
PDTA123JM	DG
PDTA123JT	*23
PDTA123JU	*43

^{[1] * =} placeholder for manufacturing site code.

PDTA123J_SER

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5. Limiting values

Table 6. Limiting values

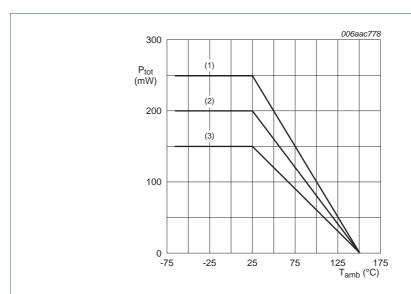
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage					
	positive			-	+5	V
	negative			-	-12	V
Io	output current			-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$				
	PDTA123JE (SOT416)		[1][2]	-	150	mW
	PDTA123JM (SOT883)		[2][3]	-	250	mW
	PDTA123JT (SOT23)		<u>[1]</u>	-	250	mW
	PDTA123JU (SOT323)		<u>[1]</u>	-	200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C
T _{stg}	storage temperature			-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70 μm copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

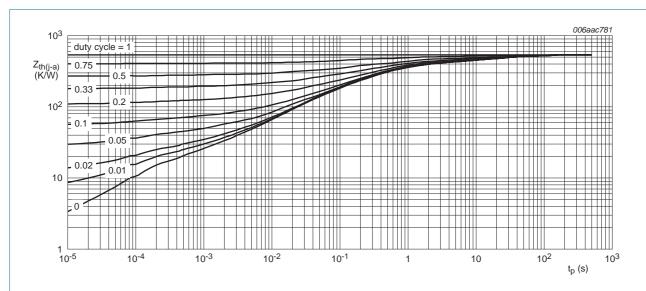
Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

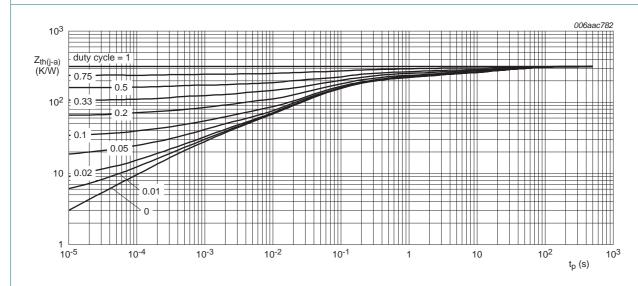
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTA123JE (SOT416)		[1][2]	-	830	K/W
	PDTA123JM (SOT883)		[2][3]	-	500	K/W
	PDTA123JT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTA123JU (SOT323)		[1] -	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



FR4 PCB, standard footprint

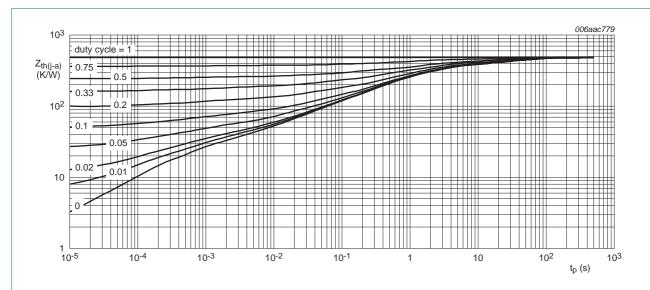
Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA123JE (SOT416); typical values



FR4 PCB, 70 µm copper strip line

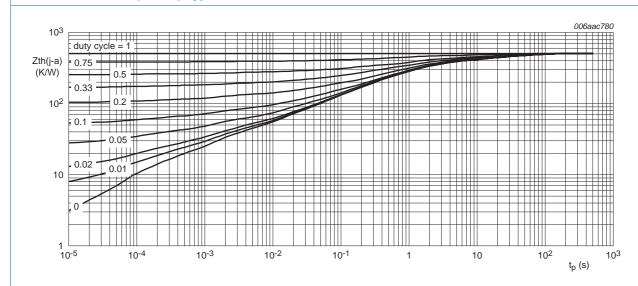
Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA123JM (SOT883); typical values

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FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA123JT (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA123JU (SOT323); typical values

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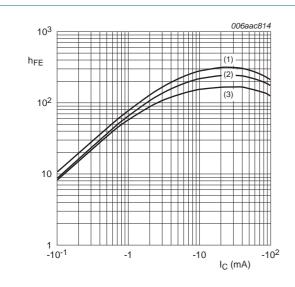
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-180	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	-	-	-100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.6	-0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_C = -5 \text{ mA}$	-1.1	-0.75	-	V
R1	bias resistor 1 (input)		1.54	2.20	2.86	kΩ
R2/R1	bias resistor ratio		17	21	26	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V; } I_{C} = -10 \text{ mA;}$ f = 100 MHz	1] -	180	-	MHz

^[1] Characteristics of built-in transistor.



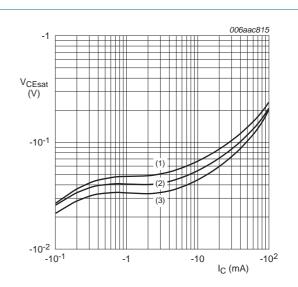
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 6. DC current gain as a function of collector current; typical values



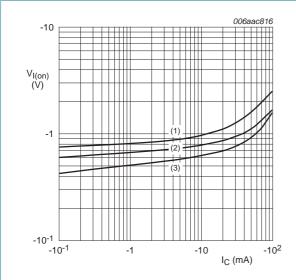
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values

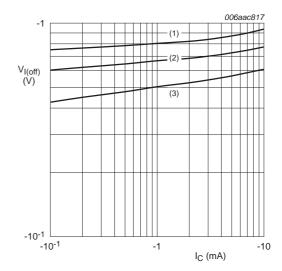


$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

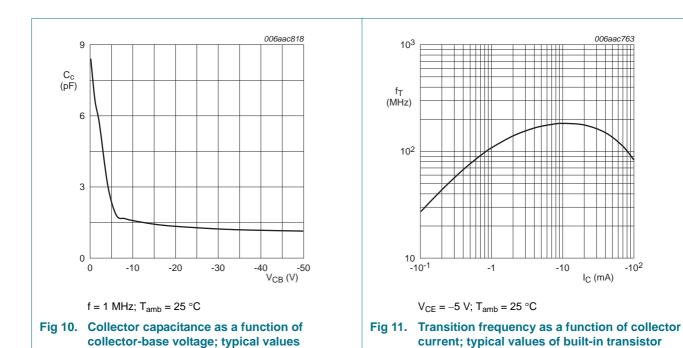
Fig 9. Off-state input voltage as a function of collector current; typical values

PDTA123J_SER

 -10^{2}

I_C (mA)

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

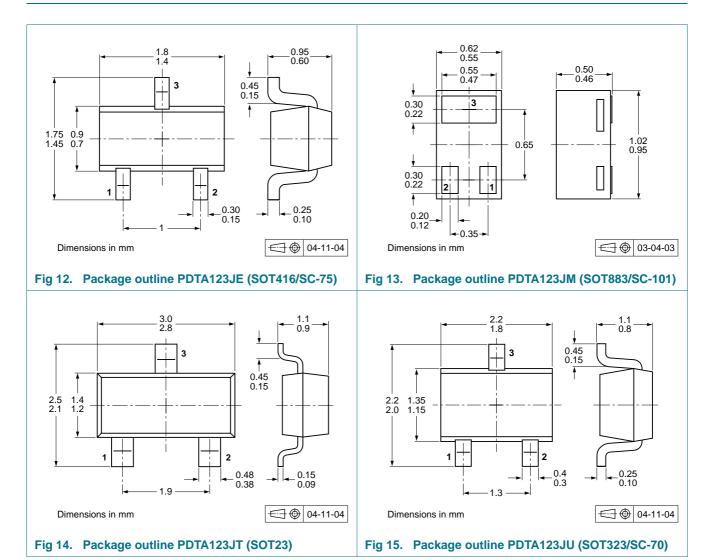


Test information 8.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

10000
10000
-135
-315
-235
-135

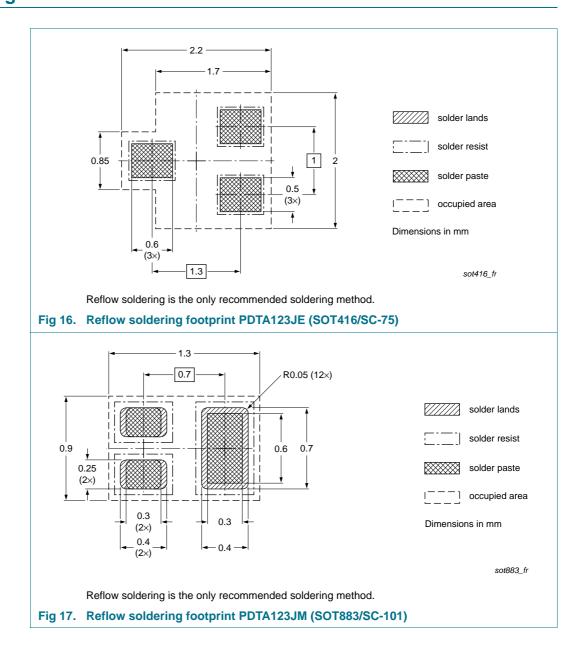
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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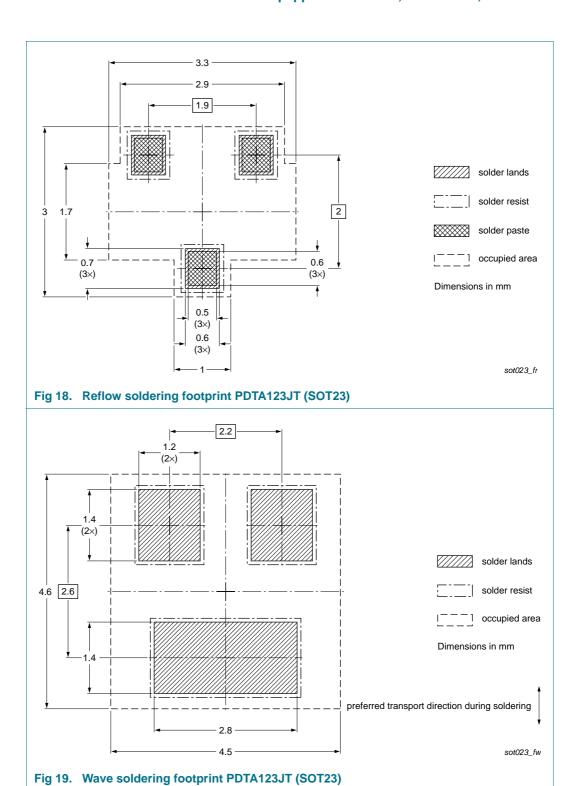
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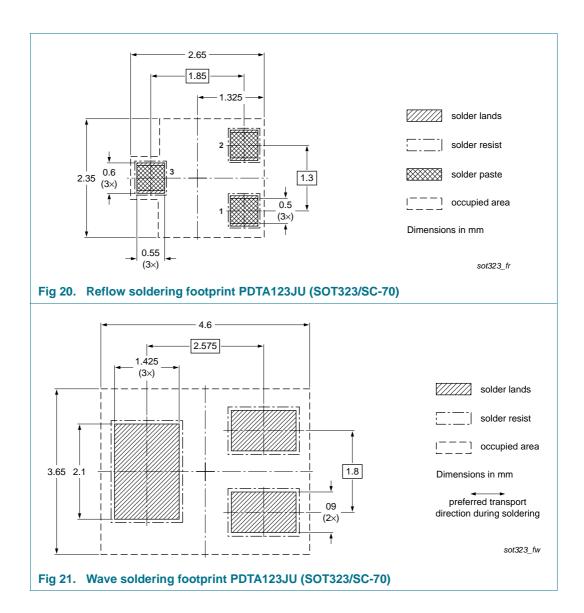
11. Soldering



11 of 17

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω





12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA123J_SER v.5	20111221	Product data sheet	-	PDTA123J_SERIES v.4
Modifications:	guidelines of N Legal texts hav Type numbers Section 1 "Pro Figure 1 to 11: Table 8 "Chara V _{I(off)} off-state Figure 12, 13, Section 8 "Tes Section 10 "Pa Section 11 "So		ew company name wh JK and PDTA123JS red to $V_{I(on)}$ on-state inpered and f_T added by minimized package of	with the new identity ere appropriate. emoved ut voltage, V _{i(off)} redefined to
PDTA123J_SERIES v.4	20040802	Product data sheet	· -	PDTA123J_SERIES v.3
PDTA123J_SERIES v.3	20030414	Product specification	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

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PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

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Date of release: 21 December 2011 Document identifier: PDTA123J_SER

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